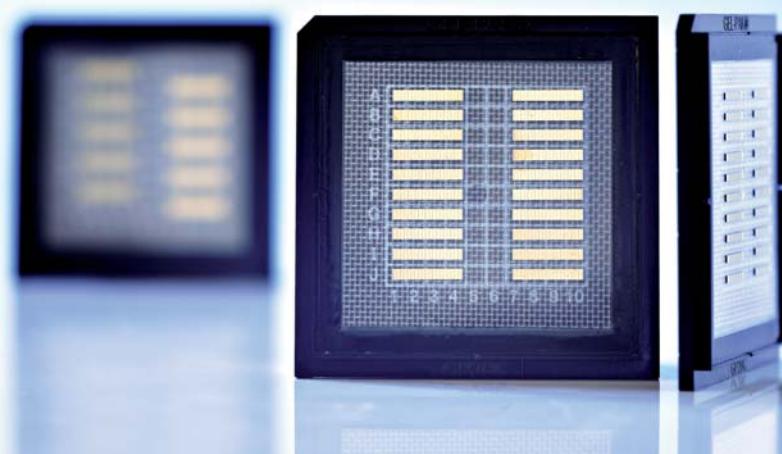




## High Power Diode Laser Bars

808 nm, 20 W cw



JDL-BAB-30-19-808-TE-20-0.6

### Features:

- High laser power
- High efficiency
- Long lifetime, high reliability
- Excellent beam characteristics

### Applications:

- Pumping of solid-state lasers and fiber lasers
- Industrial, scientific and medical systems
- Applications in the printing industry
- Defense and security

# High Power Diode Laser Bars

808 nm, 20 W cw

## Specifications

| Product                             | JDL-BAB-30-19-808-TE-20-0.6 |      |                     |       |                  |
|-------------------------------------|-----------------------------|------|---------------------|-------|------------------|
|                                     | Symbol                      | Min  | Nom                 | Max   | Unit             |
| <b>Operation*</b>                   |                             |      |                     |       |                  |
| Wavelength (cw)                     | $\lambda$                   | 798  | <b>808</b>          | 818   | nm               |
| Optical Output Power                | $P_{\text{opt}}$            |      | <b>20</b>           |       | W                |
| Operation Mode                      |                             |      | <b>cw, switched</b> |       |                  |
| Power Modulation                    |                             |      | <b>100</b>          |       | %                |
| <b>Geometrical</b>                  |                             |      |                     |       |                  |
| Number of Emitters                  |                             |      | <b>19</b>           |       |                  |
| Emitter Width                       | W                           | 145  | <b>150</b>          | 155   | $\mu\text{m}$    |
| Emitter Pitch                       | P                           |      | <b>500</b>          |       | $\mu\text{m}$    |
| Filling Factor                      | F                           |      | <b>30</b>           |       | %                |
| Bar Width                           | B                           | 9600 | <b>9800</b>         | 10000 | $\mu\text{m}$    |
| Cavity Length                       | L                           | 580  | <b>600</b>          | 620   | $\mu\text{m}$    |
| Thickness                           | D                           | 115  | <b>120</b>          | 125   | $\mu\text{m}$    |
| <b>Electro Optical Data*</b>        |                             |      |                     |       |                  |
| Fast Axis Divergence (FWHM)         | $\theta_{\parallel}$        |      | <b>36</b>           | 39    | $^{\circ}$       |
| Fast Axis Divergence**              | $\theta_{\parallel}$        |      | <b>65</b>           | 68    | $^{\circ}$       |
| Slow Axis Divergence at 20 W (FWHM) | $\theta_{\perp}$            |      | <b>7</b>            | 8     | $^{\circ}$       |
| Slow Axis Divergence at 20 W**      | $\theta_{\perp}$            |      | <b>8</b>            | 9     | $^{\circ}$       |
| Pulse Wavelength                    | $\lambda$                   | 795  | <b>805</b>          | 815   | nm               |
| Spectral Bandwidth (FWHM)           | $\Delta\lambda$             |      | <b>2</b>            | 3     | nm               |
| Slope Efficiency***                 | $\eta$                      | 1.0  | <b>1.2</b>          |       | W/A              |
| Threshold Current                   | $I_{\text{th}}$             |      | <b>4</b>            | 5     | A                |
| Operating Current                   | $I_{\text{op}}$             |      | <b>20</b>           | 25    | A                |
| Operating Voltage                   | $V_{\text{op}}$             |      | <b>1.8</b>          | 2.0   | V                |
| Series Resistance                   | $R_s$                       |      | <b>7</b>            | 9     | $\text{m}\Omega$ |
| Degree of TE Polarization           | $\alpha$                    | 98   |                     |       | %                |
| EO Conversion Efficiency***         | $\eta_{\text{tot}}$         | 50   | <b>58</b>           |       | %                |

\* Mounted on a heat sink with  $R_{\text{th}} = 0.7 \text{ K/W}$ , coolant temperature  $25^{\circ}\text{C}$ , operating at nominal power

\*\* Full width at 95 % power content

\*\*\* Item may change upon notice and acceptance by JENOPTIK Diode Lab GmbH, due to future improvements of technology or processing

Note: Nominal data represents typical values.

Safety Advices: Laser bars are the active components in high-power diode lasers in accordance to IEC standard class 4 laser products.

As delivered, laser bars cannot emit any laser beam. The laser beam can only be released if the bars are connected to a source of electrical energy. In this case, IEC-Standard 60825-1 describes the safety regulations to be taken to avoid personal injury.

Specifications may change in compliance with our quality management system.

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